SGM8261-5
High Performance, Bipolar-Input, Ultra-Low Noise HiFi Audio Headset Driver

GENERAL DESCRIPTION

The dual SGM8261-5 is a bipolar-input, low noise headset driver optimized for high voltage systems. The device operates from 3.6V to 36V single supply or from ±1.8V to ±18V dual power supplies, while consuming 4.1mA quiescent current per amplifier.

The SGM8261-5 has impressive dynamic characteristics with various loads. The rail-to-rail output swing with a 2kΩ load is within 150mV of the rails. This results in large headroom and wide dynamic range. The SGM8261-5 is unity-gain stable and offers a ±110mA high output current. It features 1.6nV/$\sqrt{Hz}$ ultra-low noise at 1kHz with 0.00002% distortion.

The SGM8261-5 is available in Green MSOP-10 and TDFN-3×3-10L packages. It operates over an ambient temperature range of -40℃ to +85℃.

FEATURES

- **Excellent Sound Quality**
- **Ultra-Low Input Voltage Noise: 1.6nV/$\sqrt{Hz}$ at 1kHz**
- **Ultra-Low Distortion: 0.00002% at 1kHz**
- **Unity-Gain Stable**
- **Gain-Bandwidth Product: 16MHz (G = +1)**
- **High Slew Rate: 16V/μs**
- **High Open-Loop Gain: 150dB**
- **Low Offset Voltage: ±350μV (MAX)**
- **Rail-to-Rail Output**
- **Support Single or Dual Power Supplies: 3.6V to 36V or ±3.6V to ±18V**
- **Low Quiescent Current: 4.1mA/Amplifier**
- **-40℃ to +85℃ Operating Temperature Range**
- **Available in Green MSOP-10 and TDFN-3×3-10L Packages**

APPLICATIONS

Professional Audio Instrument

High-End A/V Receiving Machines

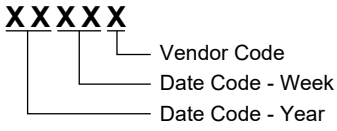
Analog and Digital Mixing Control Boards

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM8261-5	MSOP-10	-40℃ to +85℃	SGM8261-5YMS10G/TR	SGM82615 YMS10 XXXXX	Tape and Reel, 4000
	TDFN-3×3-10L	-40℃ to +85℃	SGM8261-5YTD10G/TR	SGM 82615D XXXXX	Tape and Reel, 4000

MARKING INFORMATION

NOTE: XXXXX = Date Code and Vendor Code.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, $+V_S$ to $-V_S$ 40V
Input Voltage Range ..... $(-V_S)$ - 0.3V to $(+V_S)$ + 0.3V
EN to GND ..... -0.3V to 5.5V
Input Current (All pins except power supply pins) ..... ±10mA
Output Short-Circuit Current ..... ±180mA
Junction Temperature ..... +150℃
Storage Temperature Range ..... -65℃ to +150℃
Lead Temperature (Soldering, 10s) ..... +260℃
ESD Susceptibility
HBM 8000V
MM 300V
CDM 1000V

RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range ..... -40℃ to +85℃

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

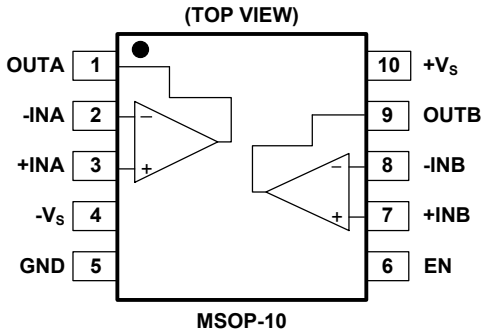
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

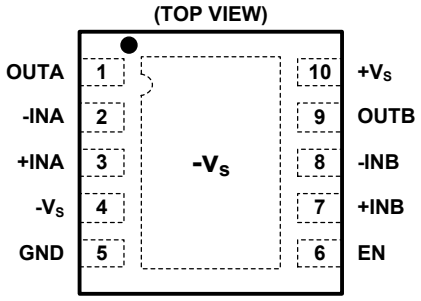
DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATIONS



MSOP-10



TDFN-3×3-10L

NOTE: For TDFN-3×3-10L package, connect thermal die pad to $-V_S$.

ELECTRICAL CHARACTERISTICS

(At T_A = +25℃, V_S = ±5V to ±18V, GND = 0V, R_L = 2kΩ, V_{CM} = V_{OUT} = V_S/2, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Input Characteristics					
Input Offset Voltage (V_{OS})	V_S = ±15V		±100	±350	μV
	-40℃ ≤ T_A ≤ +85℃			±450	
Input Offset Voltage Drift ($\Delta V_{OS}/\Delta T$)	V_S = ±15V		1		μV/℃
Input Bias Current (I_B)	V_{CM} = V_{OUT} = V_S/2		±40	±300	nA
	-40℃ ≤ T_A ≤ +85℃			±550	
Input Offset Current (I_{OS})	V_{CM} = V_{OUT} = V_S/2		±25	±165	nA
Input Common Mode Voltage Range (V_{CM})		(-V_S) + 1.8		(+V_S) - 1.8	V
Common Mode Rejection Ratio (CMRR)	V_S = ±5V, (-V_S) + 1.8V ≤ V_{CM} ≤ (+V_S) - 1.8V	114	130		dB
	-40℃ ≤ T_A ≤ +85℃	111			
	V_S = ±18V, (-V_S) + 1.8V ≤ V_{CM} ≤ (+V_S) - 1.8V	125	136		dB
	-40℃ ≤ T_A ≤ +85℃	120			
Open-Loop Voltage Gain (A_{OL})	V_S = ±5V to ±18V, (-V_S) + 0.2V ≤ V_{OUT} ≤ (+V_S) - 0.2V, R_L = 10kΩ	122	150		dB
	-40℃ ≤ T_A ≤ +85℃	119			
	V_S = ±5V to ±18V, (-V_S) + 0.6V ≤ V_{OUT} ≤ (+V_S) - 0.6V, R_L = 2kΩ	123	150		
	-40℃ ≤ T_A ≤ +85℃	120			
Input Impedance					
Differential			32k || 10		Ω || pF
Common Mode			10^9 || 4		Ω || pF
Output Characteristics					
Output Voltage Swing from Rail	V_S = ±5V to ±18V, R_L = 10kΩ		±35	±50	mV
	V_S = ±5V to ±18V, R_L = 2kΩ		±150	±210	
Output Short-Circuit Current (I_{SC})	V_S = ±3.6V to ±18V		±110		mA
Audio Performance					
Total Harmonic Distortion + Noise (THD+N)	G = +1, V_{OUT} = $3V_{RMS}$, f = 1kHz		0.00002		%
			-134		dB
Intermodulation Distortion (IMD)	G = +1, V_{OUT} = $3V_{RMS}$, SMPTE/DIN, Two-Tone, 4:1 (60Hz and 7kHz)		0.000015		%
			-136		dB
	G = +1, V_{OUT} = $3V_{RMS}$, DIM 30, (3kHz square wave and 15kHz sine wave)		0.000032		%
			-130		dB
	G = +1, V_{OUT} = $3V_{RMS}$, CCIF Twin-Tone, (19kHz and 20kHz)		0.00013		%
			-118		dB
Frequency Response					
Gain-Bandwidth Product (GBP)	G = +100		45		MHz
	G = +1		16		
Slew Rate (SR)	G = -1		16		V/μs
Full Power Bandwidth (1)	V_{OUT} = $1V_{P-P}$		2		MHz
Overload Recovery Time	G = -10		500		ns
Channel Separation (Dual)	f = 1kHz		-140		dB

NOTE: 1. Full-Power Bandwidth = Slew Rate/(2π × V_P).

ELECTRICAL CHARACTERISTICS (continued)

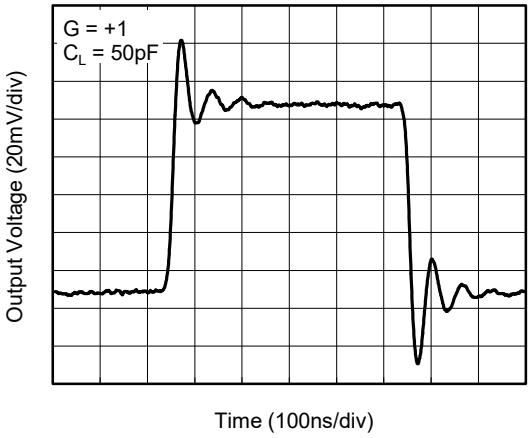
(At T_A = +25℃, V_S = ±5V to ±18V, GND = 0V, R_L = 2kΩ, V_{CM} = V_{OUT} = V_S/2, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
Noise Performance					
Input Voltage Noise	f = 20Hz to 20kHz		1.7		μV_{P-P}
Input Voltage Noise Density (e_n)	f = 10Hz		5		$nV/\sqrt{Hz}$
	f = 100Hz		2		
	f = 1kHz		1.6		
Input Current Noise Density (i_n)	f = 1kHz		6		$pA/\sqrt{Hz}$
Power Supply					
Supply Voltage (V_S)		±3.6		±18	V
Specified Voltage (V_S)		±5		±18	V
Quiescent Current/Amplifier (I_Q)	I_{OUT} = 0		4.1	5.5	mA
	-40℃ ≤ T_A ≤ +85℃			5.8	
Shutdown Current (I_{SHDN})	V_S = ±5V to ±18V, I_{OUT} = 0A, EN = GND		100	200	μA
Power Supply Rejection Ratio (PSRR)	V_S = ±3.6V to ±18V		0.1	0.6	μV/V
	-40℃ ≤ T_A ≤ +85℃			1.6	
EN Control					
Input High Voltage (V_{IH})	V_S = ±3.6V to ±18V, GND = 0V	1.8		MIN (5, +V_S)	V
Input Low Voltage (V_{IL})	V_S = ±3.6V to ±18V, GND = 0V			0.4	V
Input Leakage Current (I_{IN})	V_S = ±5V to ±18V, GND = 0V, EN = 0V or 5V		1	1.8	μA
EN Pull-Down Resistor (R_{EN})			4		MΩ

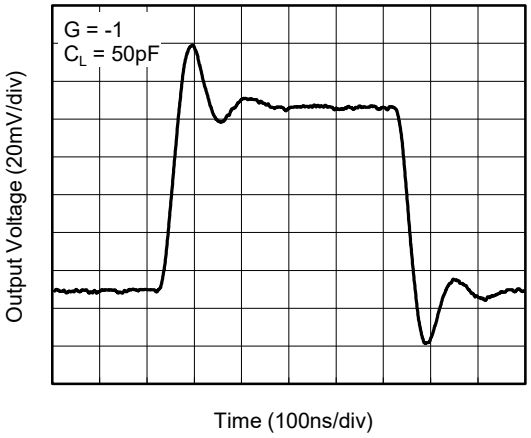
TYPICAL PERFORMANCE CHARACTERISTICS

At T_A = +25℃, V_S = ±15V, GND = 0V and R_L = 2kΩ, unless otherwise noted.

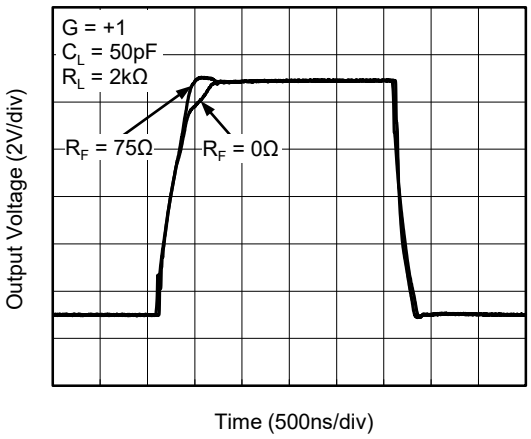
Small-Signal Step Response (100mV)



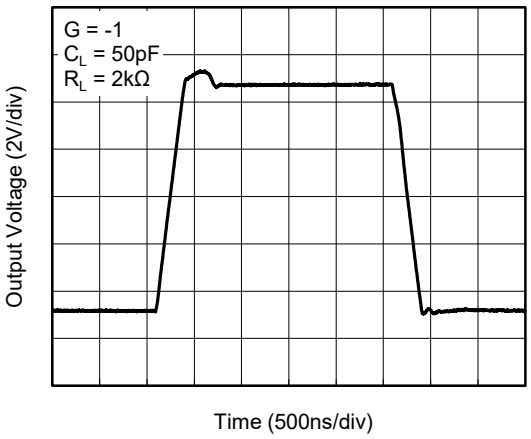
Small-Signal Step Response (100mV)



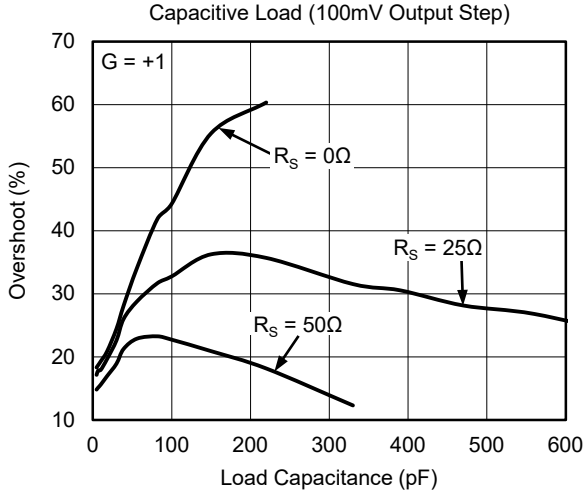
Large-Signal Step Response



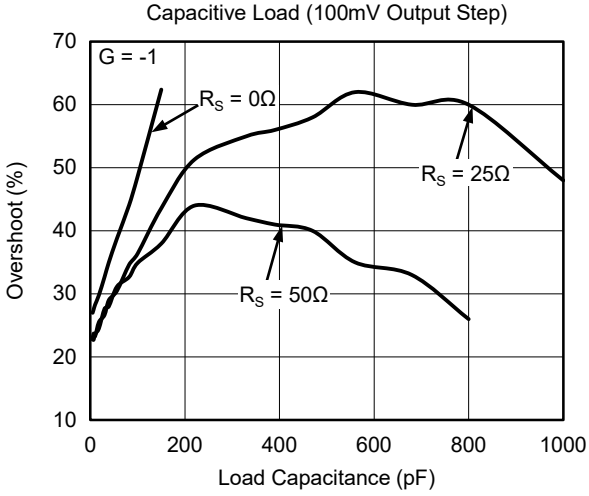
Large-Signal Step Response



Small-Signal Overshoot vs. Capacitive Load (100mV Output Step)



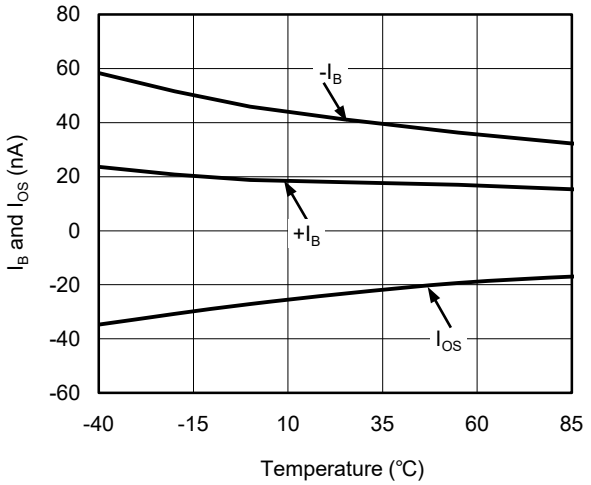
Small-Signal Overshoot vs. Capacitive Load (100mV Output Step)



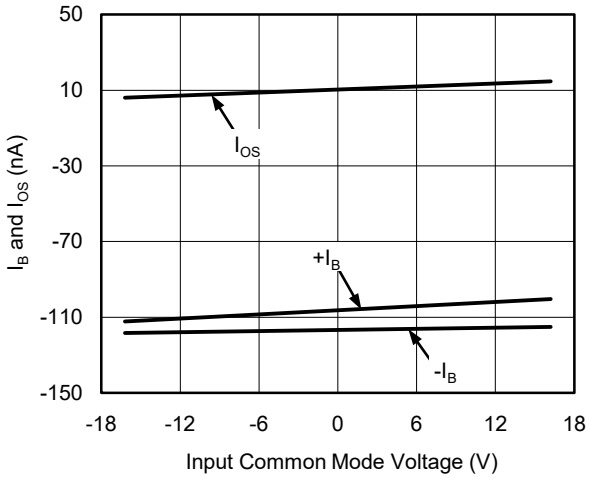
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At T_A = +25℃, V_S = ±15V, GND = 0V and R_L = 2kΩ, unless otherwise noted.

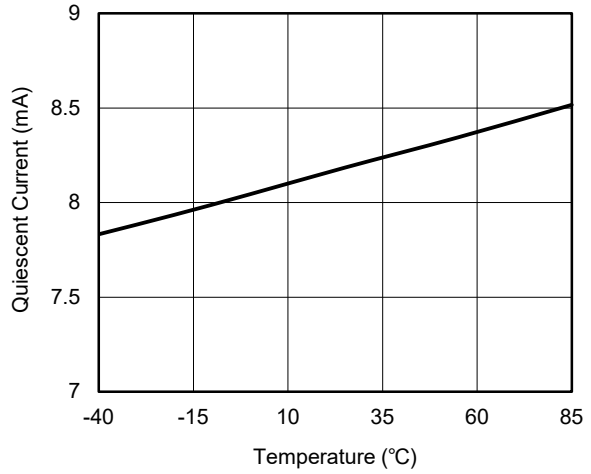
I_B and I_{OS} vs. Temperature



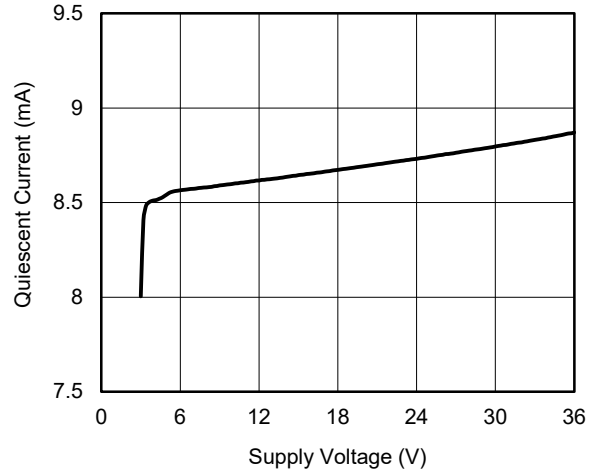
I_B and I_{OS} vs. Input Common Mode Voltage



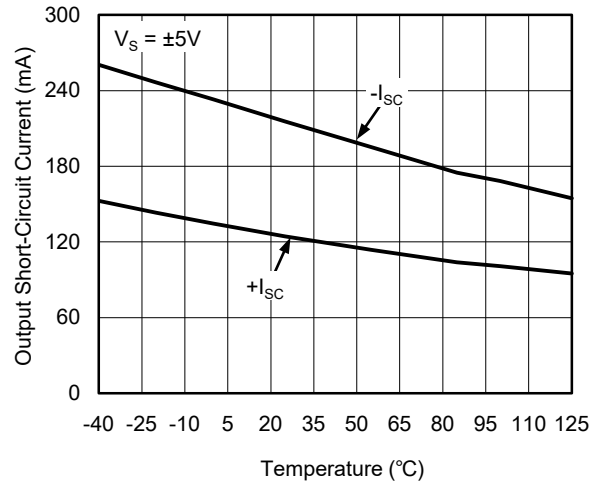
Quiescent Current vs. Temperature



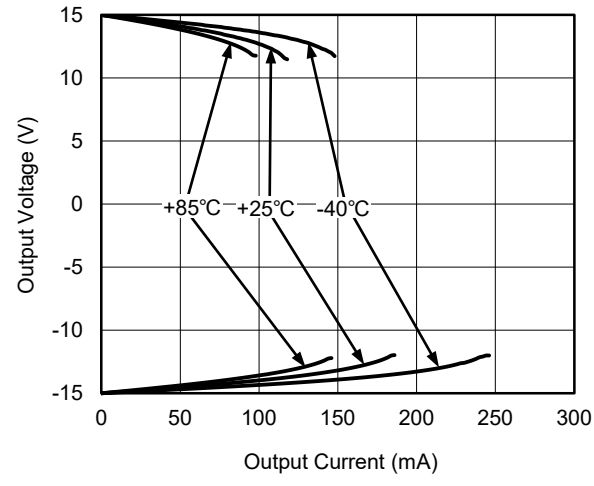
Quiescent Current vs. Supply Voltage



Output Short-Circuit Current vs. Temperature



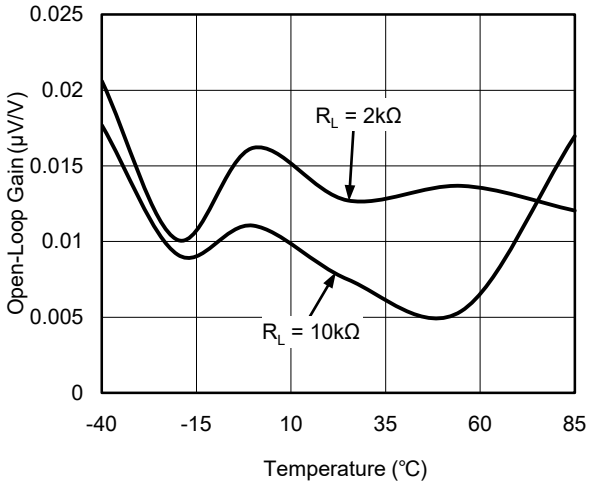
Output Voltage vs. Output Current



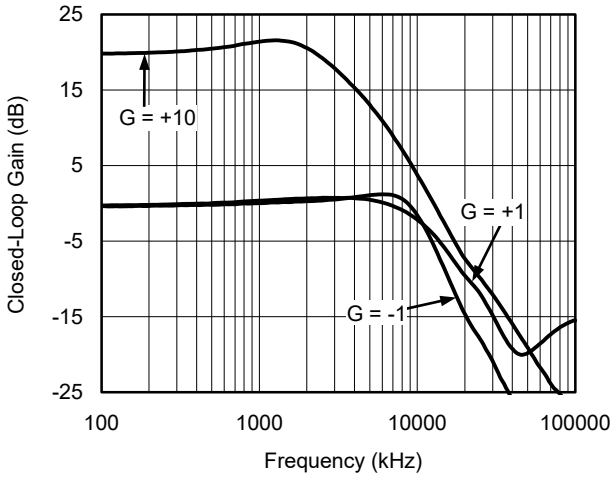
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At T_A = +25℃, V_S = ±15V, GND = 0V and R_L = 2kΩ, unless otherwise noted.

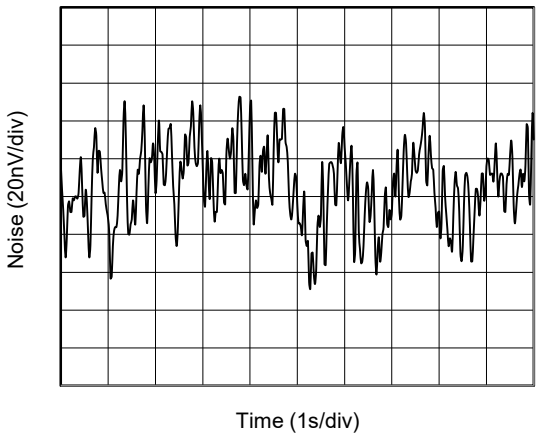
Open-Loop Gain vs. Temperature



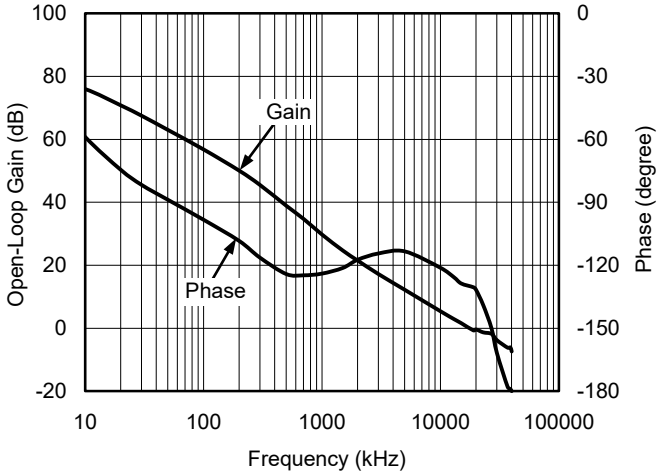
Closed-Loop Gain vs. Frequency



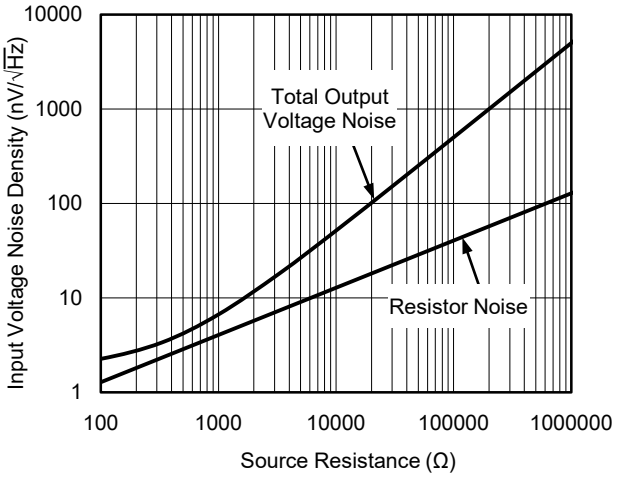
0.1Hz to 10Hz Noise



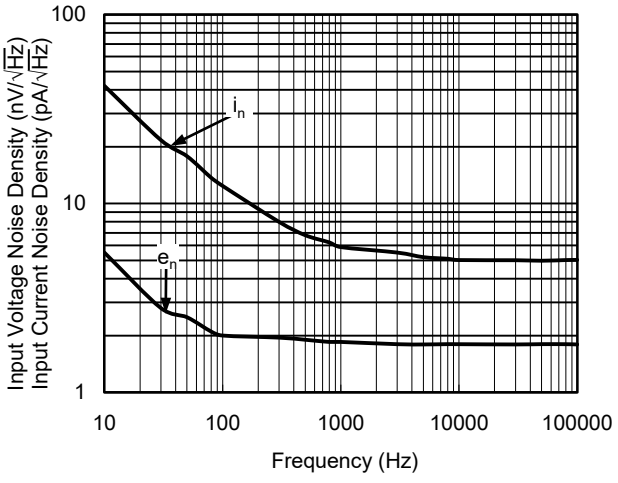
Open-Loop Gain and Phase vs. Frequency



Input Voltage Noise Density vs. Source Resistance



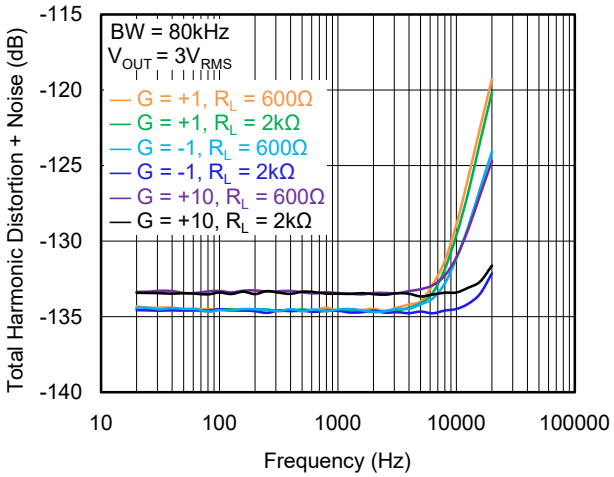
Input Voltage Noise Density (e_n) and
Input Current Noise Density (i_n) vs. Frequency



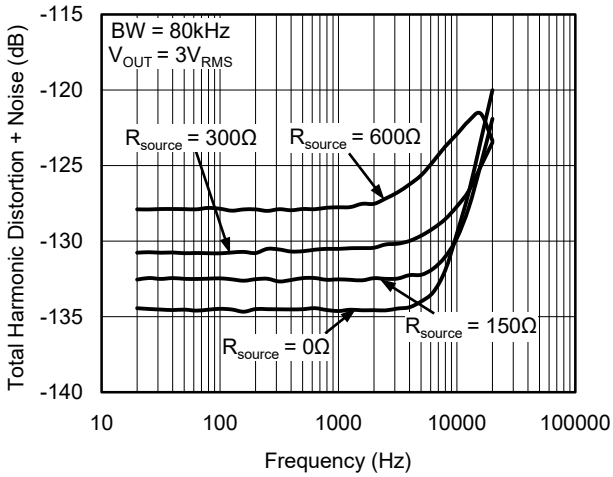
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At T_A = +25℃, V_S = ±15V, GND = 0V and R_L = 2kΩ, unless otherwise noted.

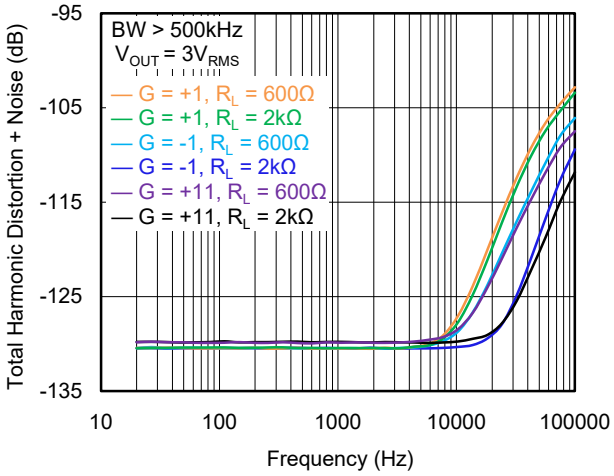
THD+N Ratio vs. Frequency



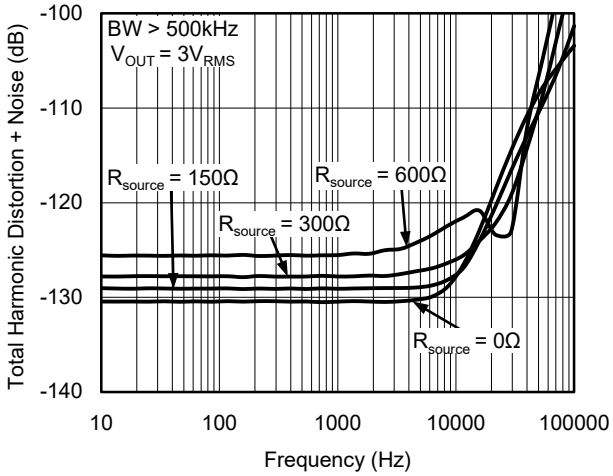
THD+N Ratio vs. Frequency



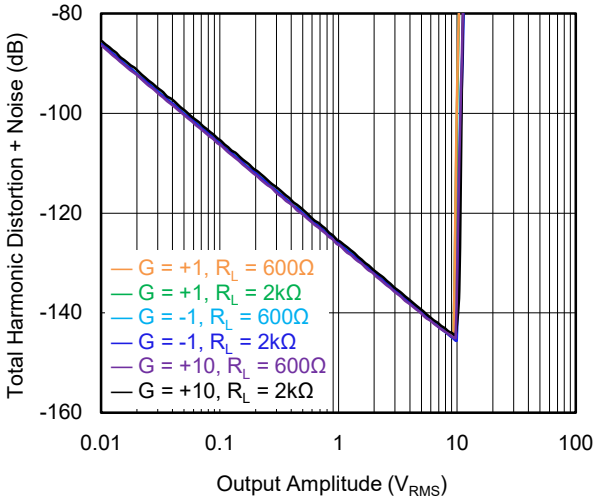
THD+N Ratio vs. Frequency



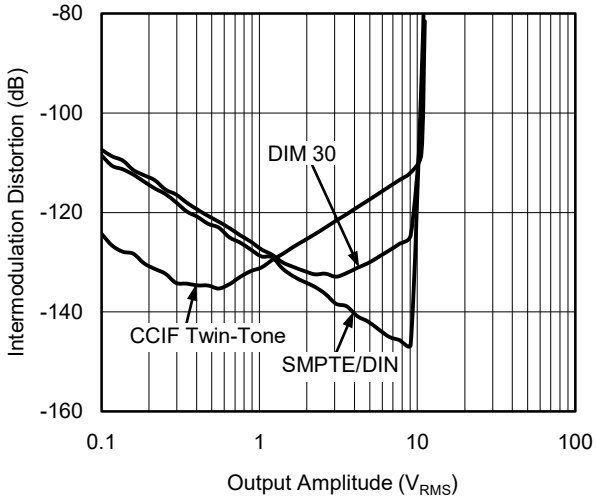
THD+N Ratio vs. Frequency



THD+N Ratio vs. Output Amplitude



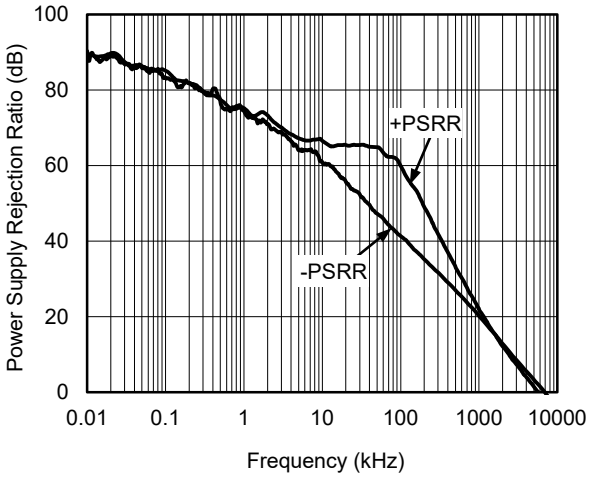
Intermodulation Distortion vs. Output Amplitude



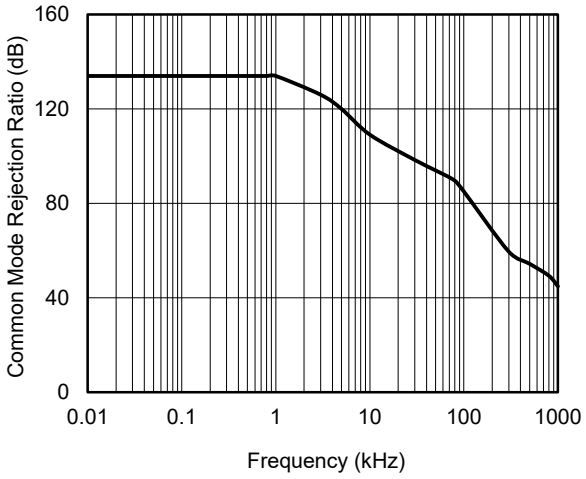
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At T_A = +25℃, V_S = ±15V, GND = 0V and R_L = 2kΩ, unless otherwise noted.

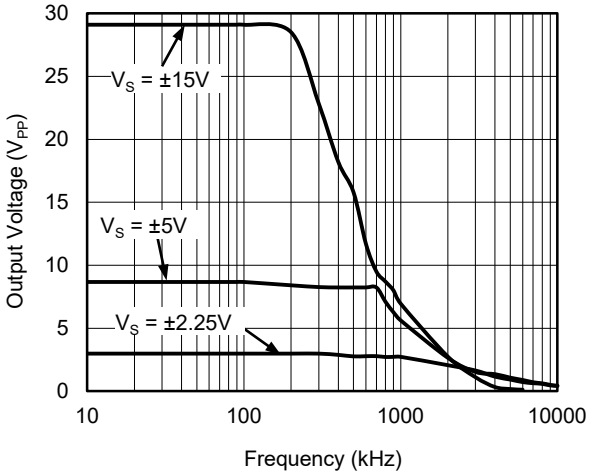
PSRR vs. Frequency (Referred to Input)



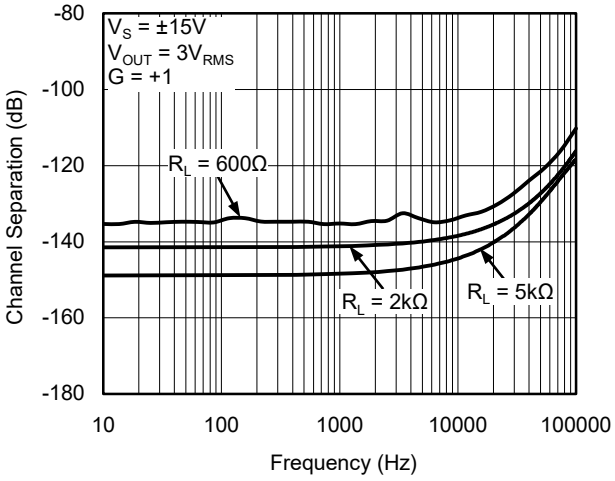
CMRR vs. Frequency (Referred to Input)



Maximum Output Voltage vs. Frequency



Channel Separation vs. Frequency



REVISION HISTORY

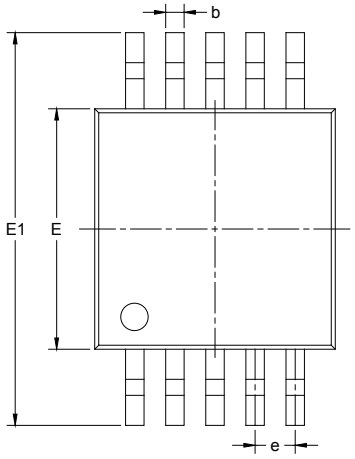
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

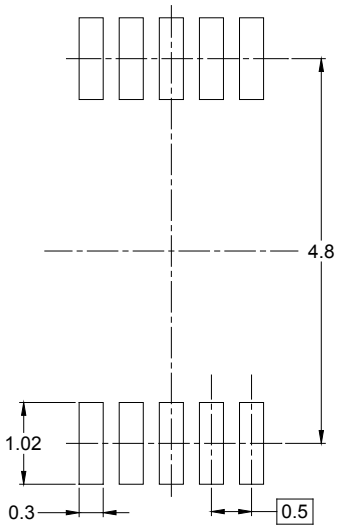
MAY 2017 – REV.A to REV.A.1	Page
Changed General Description section	1

Changes from Original (MAY 2017) to REV.A	Page
Changed from product preview to production data	All

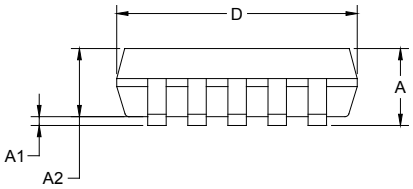
PACKAGE OUTLINE DIMENSIONS

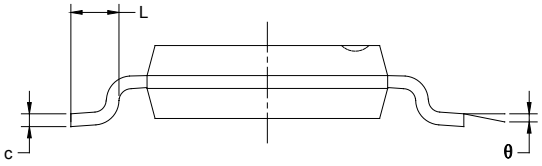
MSOP-10





RECOMMENDED LAND PATTERN (Unit: mm)

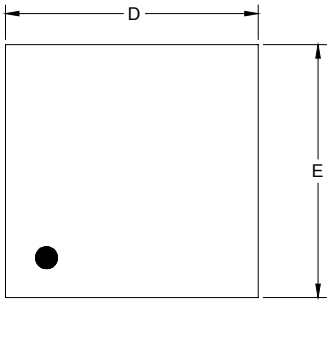




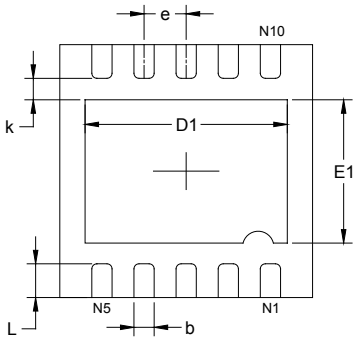
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.820	1.100	0.032	0.043
A1	0.020	0.150	0.001	0.006
A2	0.750	0.950	0.030	0.037
b	0.180	0.280	0.007	0.011
c	0.090	0.230	0.004	0.009
D	2.900	3.100	0.114	0.122
E	2.900	3.100	0.114	0.122
E1	4.750	5.050	0.187	0.199
e	0.500 BSC		0.020 BSC	
L	0.400	0.800	0.016	0.031
θ	0°	6°	0°	6°

PACKAGE OUTLINE DIMENSIONS

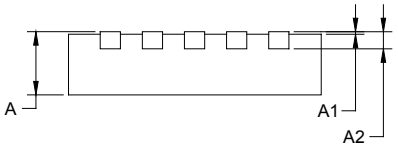
TDFN-3×3-10L



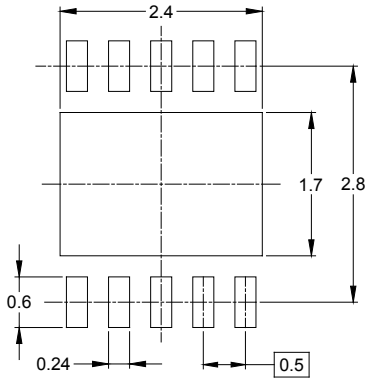
TOP VIEW



BOTTOM VIEW



SIDE VIEW

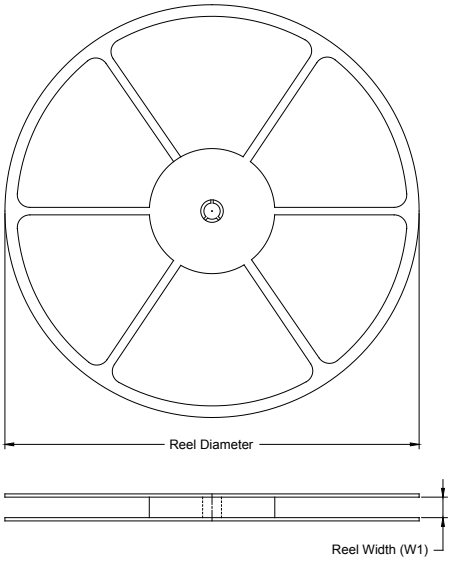


RECOMMENDED LAND PATTERN (Unit: mm)

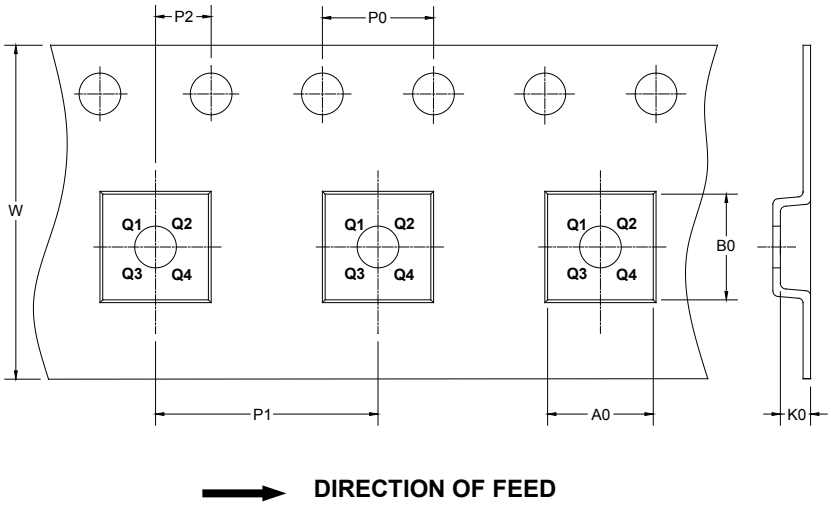
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A2	0.203 REF		0.008 REF	
D	2.900	3.100	0.114	0.122
D1	2.300	2.600	0.091	0.103
E	2.900	3.100	0.114	0.122
E1	1.500	1.800	0.059	0.071
k	0.200 MIN		0.008 MIN	
b	0.180	0.300	0.007	0.012
e	0.500 TYP		0.020 TYP	
L	0.300	0.500	0.012	0.020

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



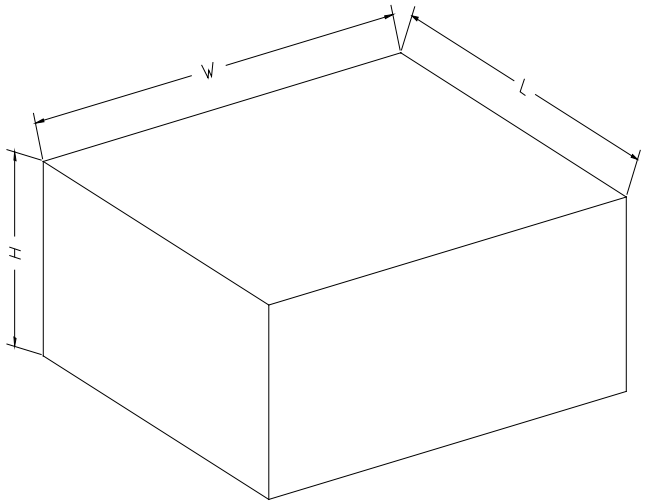
NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
MSOP-10	13″	12.4	5.20	3.30	1.20	4.0	8.0	2.0	12.0	Q1
TDFN-3×3-10L	13″	12.4	3.35	3.35	1.13	4.0	8.0	2.0	12.0	Q1

DD0001

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13″	386	280	370	5

DD0002